



DUAL 20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Package	I _D T _A = +25°C (Notes 5 & 6)
20V	$130 m\Omega$ @ $V_{GS} = 4.5 V$	MSOP-8	2.5A
200	150mΩ @ V _{GS} = 2.7V	WISOF-6	2.3A

Features

- Low On-Resistance
- Low Threshold
- Fast Switching Speed
- Low Gate Drive
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management functions
- Motor Control
- **Disconnect Switches**

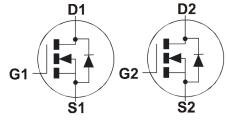
Mechanical Data

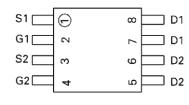
- Case: MSOP-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.0277 grams (Approximate)



Top View







Top View Device Symbol Pin-Out

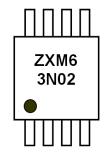
Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXMD63N02XTA	ZXM63N02	7	12	1,000
ZXMD63N02XTC	ZXM63N02	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZXM63N02 = Product type Marking Code



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

	Symbol	Value	Unit			
Drain-Source Voltage	V_{DSS}	20	V			
Gate-Source Voltage	V_{GSS}	±12	V			
Continuous Drain Current	Steady State	$@V_{GS} = 10V; T_A = +2$ $@V_{GS} = 10V; T_A = +7$ $@V_{GS} = 10V; T_A = +7$	70°C (Notes 5 & 6)	l _D	2.5 1.9 0.78	А
Pulsed Drain Current			(Notes 6 & 7)	I _{DM}	19	Α
Continuous Source Current (Body Diode)			(Notes 5 & 6)	Is	1.5	Α
Pulsed Source Current (Body Diode)			(Notes 6 & 7)	I _{SM}	19	А

Thermal Characteristics

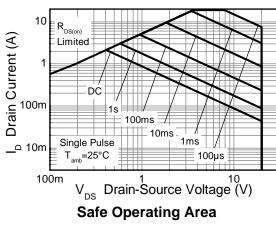
Characteristic		Symbol	Value	Unit
	(Notes 6 & 8)		0.87	
Power Dissipation	(Notes 5 & 6)	P_{D}	1.25	W
	(Notes 8 & 9)		1.04	
	(Notes 6 & 8)		143	°C/W
Thermal Resistance, Junction to Ambient	(Notes 5 & 6)	$R_{ heta JA}$	100	
	(Notes 8 & 9)		120	
Thermal Resistance, Junction to Leads	(Note 10)	R ₀ JL	84.9	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

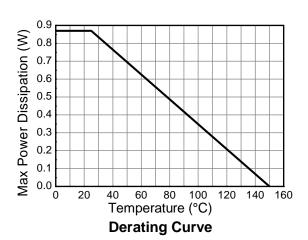
Notes:

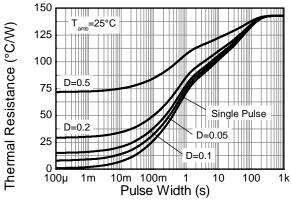
- 5. For a device surface mounted on FR4 PCB measured at $t \le 10$ sec.
- 6. For device with one active die.
- For device with one active die.
 Repetitive rating 25mm x 25mm FR4 PCB, D = 0.02, pulse width 300µs pulse width limited by maximum junction temperature.
 For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 For device with two active die running at equal power.
 Thermal resistance from junction to solder-point (at the end of the drain lead).

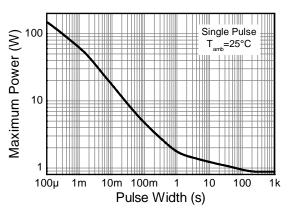


Thermal Characteristics









Transient Thermal Impedance

Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

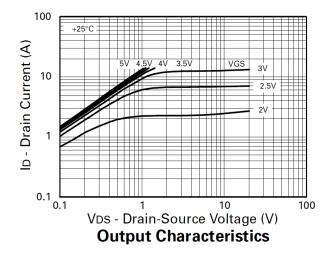
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	1.0	μΑ	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	0.7	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain Source On Registernes (Note 11)			65	130	mΩ	$V_{GS} = 4.5V, I_D = 1.7A$	
Static Drain-Source On-Resistance (Note 11)	R _{DS(ON)}	_	90	150		$V_{GS} = 2.7V, I_D = 0.85A$	
Forward Transconductance (Notes 11 & 13)	9 _{fs}	2.6	_	_	S	$V_{DS} = 10V, I_D = 0.85A$	
Diodes Forward Voltage (Note 11)	V _{SD}	_	0.85	0.95	V	$T_J = +25^{\circ}C$, $I_S = 1.7A$, $V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS							
Input Capacitance (Notes 12 & 13)	C _{iss}	_	350	700		V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance (Notes 12 & 13)	Coss	_	120	250	pF		
Reverse Transfer Capacitance (Notes 12 & 13)	C _{rss}	_	50	100		I = I.UVIHZ	
Gate Resistance (Notes 12 & 13)	Rq	_	3.8	7.6	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$	
Total Gate Charge (Notes 12 & 13)	Qg	_	4.5	6			
Gate-Source Charge (Notes 12 & 13)	Q _{gs}	_	0.5	0.65	nC	$V_{GS} = 4.5V, V_{DS} = 16V,$	
Gate-Drain Charge (Notes 12 & 13)	Q _{gd}	_	2	2.5		$I_D = 1.7A$	
Reverse Recovery Time (Note 13)	t _{rr}	_	15	30	nS	$T_J = +25^{\circ}C, I_F = 1.7A,$	
Reverse Recovery Charge (Note 13)	Q _{rr}	_	5.9	_	nC	di/dt = 100A/µs	
Turn-On Delay Time (Notes 12 & 13)	t _{D(on)}	_	3.4	_			
Turn-On Rise Time (Notes 12 & 13)	t _r	_	8.1	_	- 0	$V_{DD} = 10V, I_D = 1.7A,$	
Turn-Off Delay Time (Notes 12 & 13)	t _{D(off)}	_	13.5	_	nS	$R_G = 6\Omega$, $R_D = 5.7\Omega$,	
Turn-Off Fall Time (Notes 12 & 13)	t _f	_	9.1	_			

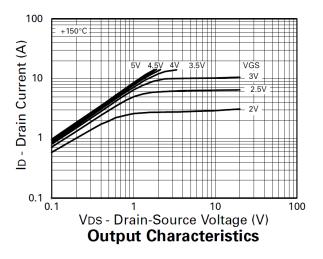
Notes:

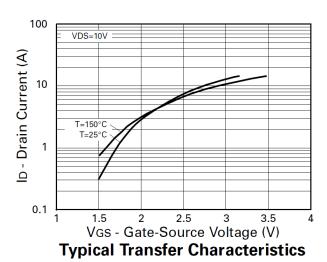
- 11. Measured under pulsed conditions. Pulse width \leq 300µs; duty cycle \leq 2%.
- 12. Switching characteristics are independent of operating junction temperature.13. For design aid only, not subject to production testing.

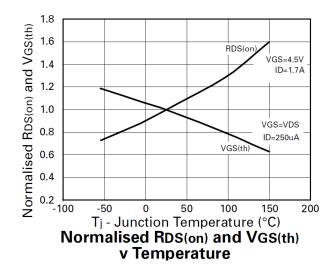


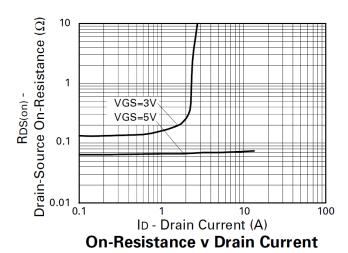
Typical Characteristics

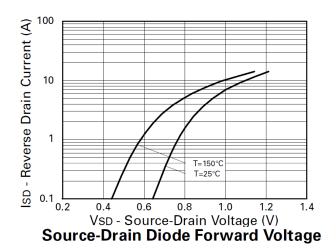






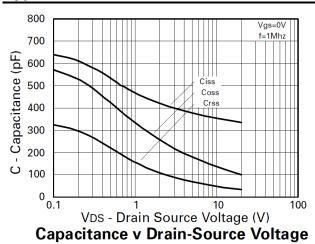


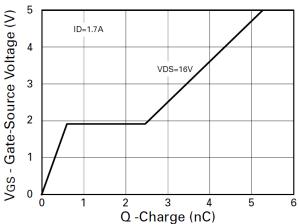






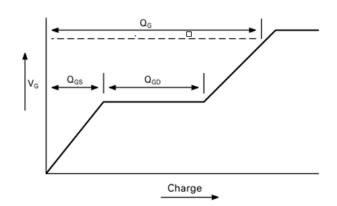
Typical Characteristics (Continued)



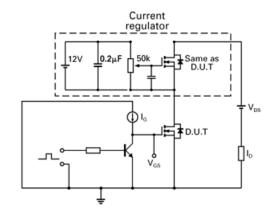


Gate-Source Voltage v Gate Charge

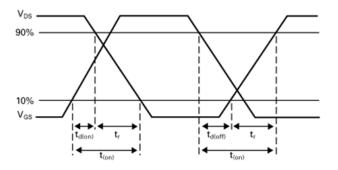
Test Circuits



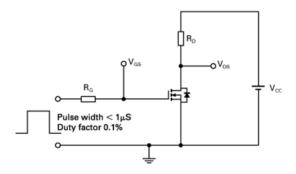
Basic gate charge waveform



Gate charge test circuit



Switching time waveforms



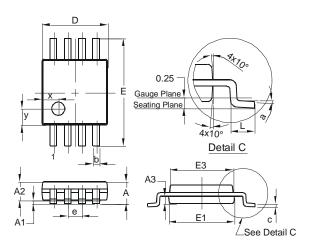
Switching time test circuit



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

MSOP-8

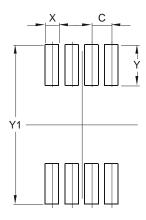


MSOP-8					
Dim	Min	Max	Тур		
A	ı	1.10	_		
A1	0.05	0.15	0.10		
A2	0.75	0.95	0.86		
А3	0.29	0.49	0.39		
b	0.22	0.38	0.30		
С	0.08	0.23	0.15		
D	2.90	3.10	3.00		
Е	4.70	5.10	4.90		
E1	2.90	3.10	3.00		
E3	2.85	3.05	2.95		
е	_	_	0.65		
J	0.40	0.80	0.60		
а	0°	8°	4°		
Х	-	-	0.750		
у	-	-	0.750		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

MSOP-8



Dimensions	Value (in mm)
С	0.650
Х	0.450
Υ	1.350
Y1	5.300



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: ZXMD63N02XTA